# NSN 5962-01-165-3122

Memory Microcircuit - Page 1 of 1



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## Body Length:

1.290 inches

#### **Body Width:**

0.600 inches

## Body Height:

0.180 inches

## **Maximum Power Dissipation Rating:**

53.0 milliwatts

#### **Operating Tempurature Range:**

-25.0/+85.0 degrees celsius

## Storage Tempurature Range:

-65.0/+125.0 degrees celsius

## **End Application:**

5865-01-096-4994 radar simulator

#### **Features Provided:**

Programmable and ultraviolet erasable and static operation and 3-state output and high speed

#### Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

## Output Logic Form:

Complementary-metal oxide-semiconductor logic

## Input Circuit Pattern:

14 input

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

6.0 volts power source

## Time Rating Per Chacteristic:

450.00 nanoseconds propagation delay time, low to high level output

#### Memory Device Type:

Rom

## Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

## Fiig:

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